Pressfit Rectifier Diodes, 50 A



B-47

FEATURES

- Convenient pressfit package
- Available with and without leads
- High surge capabilities
- Fully characterized bulletin
- RoHS compliant
- Designed and qualified for industrial level

PRODUCT SUMMARY				
I _{F(AV)}	50 A			

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
I _{F(AV)}		50	А	
	T _C	150	°C	
I _{F(RMS)}		79	А	
I _{FSM}	50 Hz	714	۸	
	60 Hz	747	A	
l ² t	50 Hz	2546	A ² s	
	60 Hz	2324	A-S	
l²√t		25 455	A²√s	
V _{RRM}	Range	50 to 400	V	
TJ		- 65 to 195	°C	

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS					
TYPE NUMBER	PEAK REVERSE VOLTAGE		V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = T _J MAXIMUM mA	
	05 50		75	7	
8AF	1	100	150	7	
	2	200	300	5	
	4	400	500	5	



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FORWARD CONDUCTION							
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS		
Maximum average forward current	I _{F(AV)}	180° conduction, half sine wave		180° conduction, half sine wave		50	А
at case temperature	. ,				150	°C	
Maximum RMS forward current	I _{F(RMS)}				79	Α	
Maximum peak, one cycle forward, non-repetitive surge current	I _{FSM}	t = 10 ms	No voltage	Sinusoidal half wave,	714	А	
		t = 8.3 ms	reapplied		747		
		t = 10 ms	100 % V _{RRM} reapplied		600		
		t = 8.3 ms			628		
	l ² t	t = 10 ms	No voltage	initial TJ = TJ maximum	2546	A ² s	
Maximum I ² t for fusing		t = 8.3 ms	reapplied	-	2324		
Maximum i-t for fusing		t = 10 ms	100 % V _{RRM}		1800		
		t = 8.3 ms	reapplied		1643		
Maximum $I^2 \sqrt{t}$ for fusing	l²√t	t = 0.1 to 10 ms, no voltage reapplied		25 455	A²√s		
Low level value of threshold voltage	V _{F(TO)1}	$(16.7 \% x \pi x I_{F(AV)} < I < \pi x I_{F(AV)}), T_J = T_J maximum$		0.60	V		
High level value of threshold voltage	V _{F(TO)2}	$(\pi x _{F(AV)} < I < 20 x \pi x _{F(AV)}), T_J = T_J maximum$		0.68	v		
Low level value of forward slope resistance	r _{f1}	$(16.7 \% x \pi x I_{F(AV)} < I < \pi x I_{F(AV)}), T_J = T_J maximum$		6.66	mΩ		
High level value of forward slope resistance	r _{f2}	$(\pi x I_{F(AV)} < I < 20 x \pi x I_{F(AV)}), T_J = T_J maximum$			6.25	1112.2	
Maximum forward voltage drop	V _{FM}	$T_{J} = 25 \text{ °C}, I_{FM} = \pi \text{ x rated } I_{F(AV)}$ 1.45			V		

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS		UNITS	
Maximum junction operating and storage temperature range	T _J , T _{Stg}		- 65 to 195	°C	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.60	K/W	
Typical thermal resistance, case to heatsink	R _{thCS}	As per mounting details, see note ⁽¹⁾	0.50		
Approximate weight			10	g	
		0.36	oz.		
Case style		See dimensions - link at the end of datasheet	B-47		

Note

⁽¹⁾ Mounting: A 12.6 \pm 0.02 mm (0.496 to 0.497") diameter hole should be drilled in heatsink, the leading edge chamfered to 0.038 mm (0.015") x 45°. The autodiode should then be press fitted, ensuring that the sides of the autodiode are kept parallel to the sides of the hole.



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CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS		
180°	0.042	0.026				
120°	0.045	0.043				
90°	0.06	0.06	$T_J = T_J maximum$	K/W		
60°	0.10	0.10				
30°	0.15	0.15				

Note

• The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

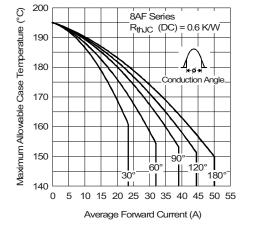


Fig. 1 - Current Ratings Characteristics

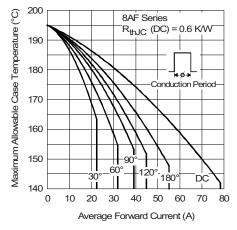


Fig. 2 - Current Ratings Characteristics

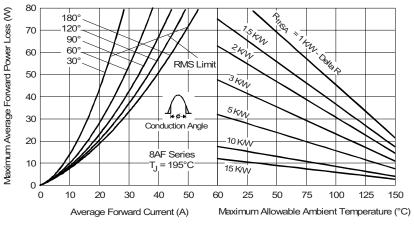
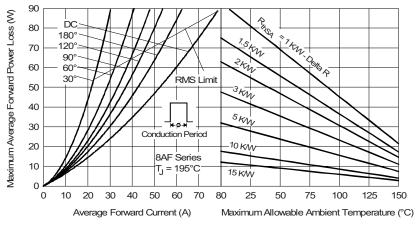
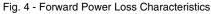


Fig. 3 - Forward Power Loss Characteristics

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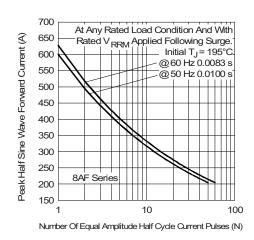


Fig. 5 - Maximum Non-Repetitive Surge Current

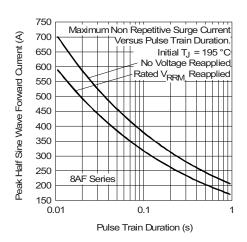


Fig. 6 - Maximum Non-Repetitive Surge Current

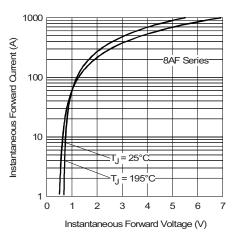


Fig. 7 - Forward Voltage Drop Characteristics

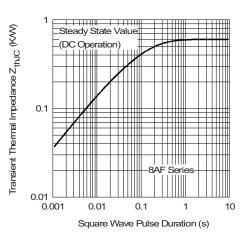
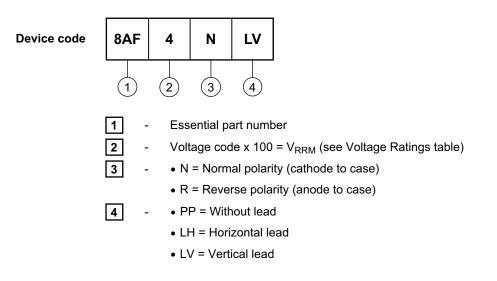


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics



ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS		
Dimensions	http://www.vishay.com/doc?95330	



Outline Dimensions

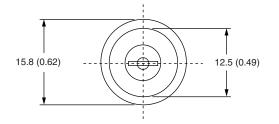
Vishay Semiconductors

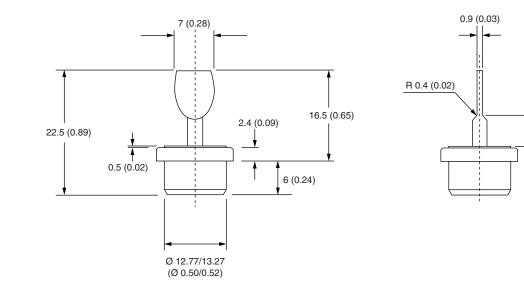
5 (0.20)

1

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DIMENSIONS in millimeters (inches)







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